

September 2012

# FFH75H60S Hyperfast Recovery Power Rectifier

#### **Features**

- High Speed Switching (t<sub>rr</sub>=40ns(Typ.) @ I<sub>F</sub>=75A)
- · High Reverse Voltage and High Reliability
- · Avalanche Energy Rated
- Low Forward Voltage(V<sub>F</sub>=1.8V(Typ.) @ I<sub>F</sub>=75A)

### **Applications**

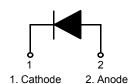
- · General Purpose
- · Switching Mode Power Supply
- · Power switching circuits

### 75A, 600V Hyperfast Rectifier

The FFH75H60S is a hyperfast diode with soft recovery characteristics (trr< 40ns). It has half the recovery time of ultrafast diodes and is of silicon nitride passivated ion-implanted epitaxial planar construction. This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits, thus reducing powerloss in the switching transistors.

### **Pin Assignments**





# Absolute Maximum Ratings $_{T_C = 25^{\circ}C \text{ unless otherwise noted}}$

Symbol	Parameter	Ratings	Units	
V <sub>RRM</sub>	Peak Repetitive Reverse Voltage	600	V	
V <sub>RWM</sub>	Working Peak Reverse Voltage	600	V	
V <sub>R</sub>	DC Blocking Voltage	600	V	
I <sub>F(AV)</sub>	Average Rectified Forward Current @ T <sub>C</sub> = 105°C	75	А	
I <sub>FSM</sub>	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	750	А	
T <sub>J,</sub> T <sub>STG</sub>	Operating Junction and Storage Temperature	- 65 to +150	°C	

# Thermal Characteristics $_{T_C = 25^{\circ}\text{C unless otherwise noted}}$

Symbol	Parameter Max		Units	
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	0.4	°C/W	

### **Package Marking and Ordering Information**

Device Marking Device		Package	Reel Size	Tape Width	Quantity
FFH75H60S	FFH75H60S	TO-247-2L	-	-	30

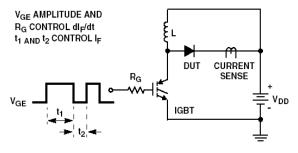
### **Electrical Characteristics** $T_C = 25^{\circ}C$ unless otherwise noted

Parameter	Conditions		Min.	Тур.	Max	Units
V <sub>FM</sub> <sup>1</sup>	I <sub>F</sub> = 75A I <sub>F</sub> = 75A	T <sub>C</sub> = 25 °C T <sub>C</sub> = 125 °C	-	1.8 1.6	2.2 2.0	V V
I <sub>RM</sub> <sup>1</sup>	V <sub>R</sub> = 600V V <sub>R</sub> = 600V	$T_C = 25  ^{\circ}C$ $T_C = 125  ^{\circ}C$	-	-	100 1.0	μA mA
t <sub>rr</sub>	$I_F = 75A$ , di/dt = 200A/ $\mu$ s, $V_{CC} = 390V$	T <sub>C</sub> = 25 °C T <sub>C</sub> = 125 °C	-	40 85	75 -	ns ns
t <sub>a</sub> t <sub>b</sub> Q <sub>rr</sub>	$I_F = 75A$ , di/dt = 200A/ $\mu$ s, $V_{CC} = 390V$	$T_C = 25 \degree C$ $T_C = 25 \degree C$ $T_C = 25 \degree C$	- - -	23 17 80	- - -	ns ns nC
W <sub>AVL</sub>	Avalanche Energy (L = 40mH)	•	20	-	-	mJ

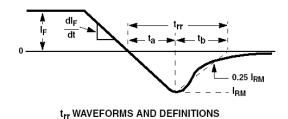
#### Notes:

1. Pulse : Test Pulse width =  $300\mu s$ , Duty Cycle = 2%

### **Test Circuit and Waveforms**



t<sub>rr</sub> TEST CIRCUIT



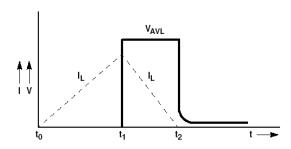
I<sub>MAX</sub> = 1A L = 40mH R < 0.1Ω E<sub>AVL</sub> = 1/2LI<sup>2</sup> [V<sub>R(AVL)</sub>/(V<sub>R(AVL)</sub> - V<sub>DD</sub>)] Q<sub>1</sub> = IGBT (BV<sub>CES</sub> > DUT V<sub>R(AVL)</sub>) CURRENT SENSE

V<sub>DD</sub>

V<sub>DD</sub>

V<sub>DD</sub>

AVALANCHE ENERGY TEST CIRCUIT



AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

### **Typical Performance Characteristics**

Figure 1. Typical Forward Voltage Drop vs. Forward Current

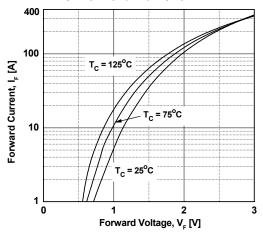


Figure 3. Typical Junction Capacitance

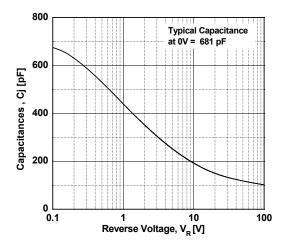


Figure 5. Typical Reverse Recovery Current vs. di/dt

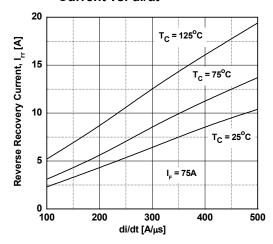


Figure 2. Typical Reverse Current vs.

Reverse Voltage

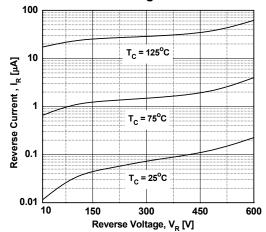


Figure 4. Typical Reverse Recovery Time vs. di/dt

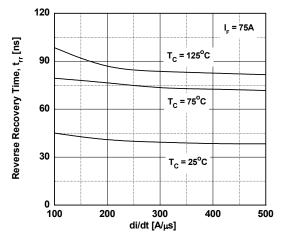
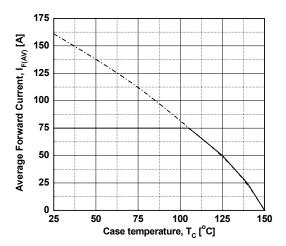
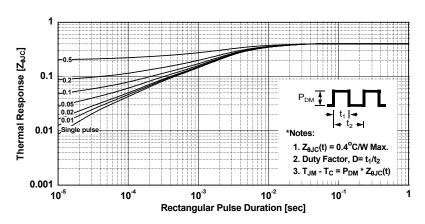


Figure 6. Forward Current Derating Curve



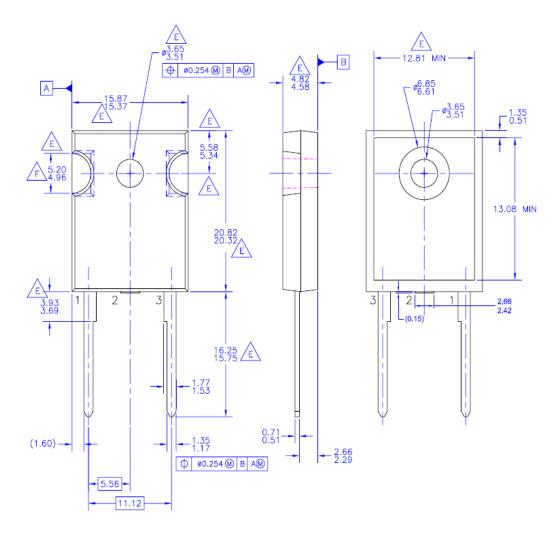
## **Typical Performance Characteristics** (Continued)





### **Mechanical Dimensions**

# TO-247-2L



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Dimensions in Millimeters





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